# MSKSEMI 美森科













ESD

TVS

TSS

MOV

GDT

PLED

# CDB0130QRM-MS

Product specification





#### **Features**

- Ultra Small mold type. SOD-923
- Low IR
- High reliability

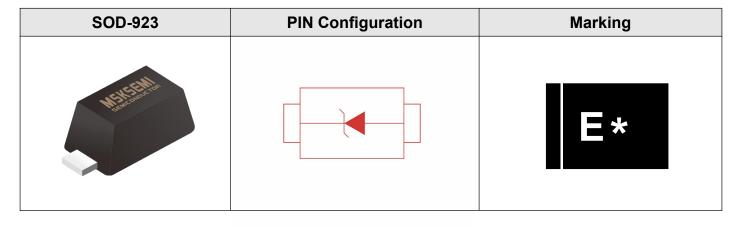
# **Applications**

Low current rectification

#### **Mechanical Characteristics**

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- Pure tin plating: 7 ~ 17 um
- Pin flatness:≤3mil

#### **Reference News**



# Electrical characteristics per line@25℃

Parameter	Symbol	Min.	Тур.	Max.	Unit	Conditions
Forward voltage	VF	-	0.27	0.31	V	l≔ 1mA
Forward voltage	VF	-	0.30	0.35	V	l≔ 10mA
Forward voltage	VF		0.36	0.40	V	I=20mA
Forward voltage	VF	-	0.48	0.55	V	l≔ 100mA
Reverse current	lR	-	-	1.5	μΑ	V <sub>R</sub> = 10V

# Absolute maximum rating@25° $\mathbb C$

Parameter	Symbol limits		Unit	
Reverse voltage (DC)	Vrm	30	V	
Average rectified forward current	lo	100	mA	
Forward current surge peak (60Hz 1cyc)	IFSM	500	mA	
Operating Junction temperature Range	Tj	-55 to 125	$^{\circ}$	
Storage temperature	T <sub>stg</sub>	-40 to +125	$^{\circ}$	

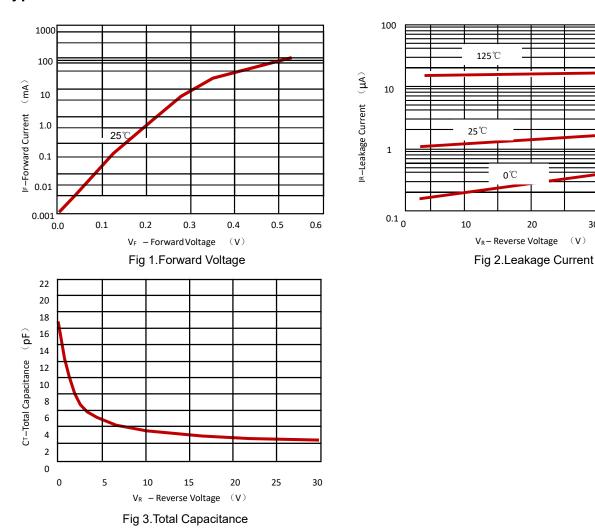
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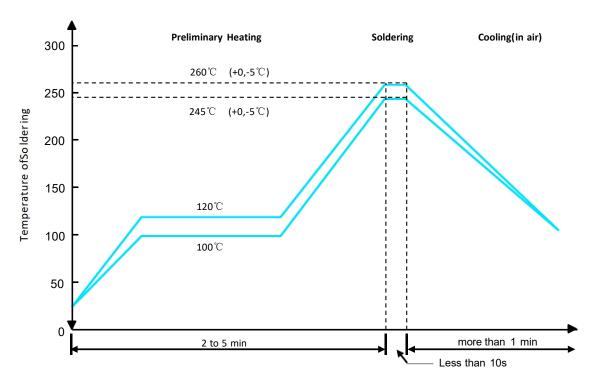
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# **TypicalCharacteristics**



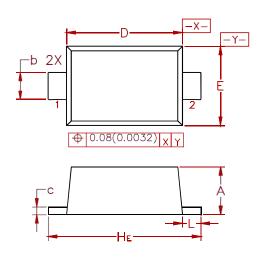
## SolderReflowRecommendation



Remark: Pb free for 260°C; Pb for 245°C.



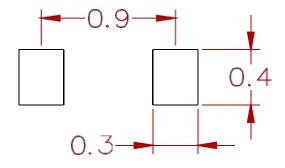
## **PACKAGEMECHANICALDATA**



Dim	Millimeters			Inches		
	Min	Nom	Max	Min	Nom	Max
Α	0.36	0.40	0.43	0.	0.016	0.017
b	0.15	0.20	0.25	0140.	0.008	0.010
С	0.07	0.12	0.17	0060.	0.005	0.007
D	0.75	0.80	0.85	0030.	0.031	0.033
E	0.55	0.60	0.65	0300.	0.024	0.026
HE	0.95	1.00	1.05	0220.	0.039	0.041
L	0.05	0.10	0.15	0370.	0.004	0.006

002

# Suggested Pad Layout



**Dimensions: Millimeters** 

# **Order information**

Orderable Device	Package	Packing Option
CDB0130QRM-MS	SOD-923	8000PCS



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